TECHNICAL DATA DATA SHEET 1019, REV. A

## SILICON SCHOTTKY RECTIFIER DIE **Very Low Forward Voltage Drop (150 °C T<sub>J</sub> Operation)**

## Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

### Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
  Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Electrically / Mechanically Stable during and after Packaging

## **Maximum Ratings**(1):

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	60	V
Max. Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle, rectangular wave form	1	А
Max. Peak One Cycle Non- Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine wave	20	А
Non-Repetitive Avalanche Energy	E <sub>AS</sub>	$T_J = 25  ^{\circ}\text{C}, \ I_{AS} = 0.74  \text{A}, \ L = 18  \text{mH}$	5.0	mJ
Repetitive Avalanche Current	$I_{AR}$	$I_{AS}$ decay linearly to 0 in 1 $\mu$ s $f$ limited by $T_J$ max $V_A$ =1.5 $V_R$	0.74	А
Max. Junction Temperature	$T_J$	-	-65 to +150	°C
Max. Storage Temperature	$T_{stg}$	-	-65 to +150	°C

## Electrical Characteristics(1):

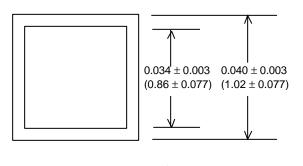
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	$V_{F1}$	@ 1A, Pulse, T <sub>J</sub> = 25 °C	0.56	V
	$V_{F2}$	@ 1A, Pulse, T <sub>J</sub> = 125 °C	0.51	V
Max. Reverse Current	I <sub>R1</sub>	@V <sub>R</sub> = 60V, Pulse,	100	μΑ
		T <sub>J</sub> = 25 °C		
	$I_{R2}$	$@V_R = 60V$ , Pulse,	9.0	mA
		T <sub>J</sub> = 125 °C		
Max. Junction Capacitance	$C_T$	$@V_R = 5V, T_C = 25  ^{\circ}C$	53	pF
		$f_{SIG} = 1MHz,$		
		$V_{SIG} = 50 \text{mV (p-p)}$		

(1) in SHD package

<sup>•</sup> World Wide Web Site - http://www.sensitron.com • E-Mail Address - sales@sensitron.com •

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### Mechanical Dimensions: In Inches / mm

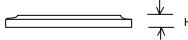


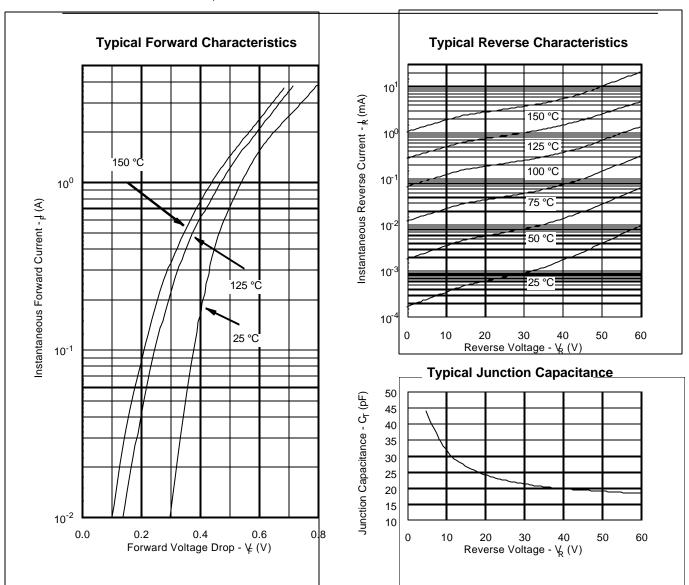
Bottom side metalization Ag - 30 kÅ minimum.

Top side metalization Al - 25 kÅ minimum or Ag - 30 kÅ minimum.

Bottom side is cathode, top side is anode.

Dimension H =  $0.0105 \pm 0.001$  (0.27  $\pm 0.026$ ) for Al top; Dimension H =  $0.0155 \pm 0.001$  (0.39  $\pm 0.026$ ) for Ag top.





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